FAIRCHILD

SEMICONDUCTOR®

BD434/436/438

Medium Power Linear and Switching Applications

Complement to BD433, BD435 and BD437 respectively



PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage		
	: BD434	- 22	V
	: BD436	- 32	V
	: BD438	- 45	V
V _{CES}	Collector-Emitter Voltage		
	: BD434	- 22	V
	: BD436	- 32	V
	: BD438	- 45	V
V _{CEO}	Collector-Emitter Voltage		
	: BD434	- 22	V
	: BD436	- 32	V
	: BD438	- 45	V
V _{EBO}	Emitter-Base Voltage	- 5	V
c	Collector Current (DC)	- 4	А
I _{CP}	*Collector Current (Pulse)	- 7	А
I _B	Base Current	- 1	А
P _C	Collector Dissipation (T _C =25°C)	36	W
Т _Ј	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 65 ~ 150	°C

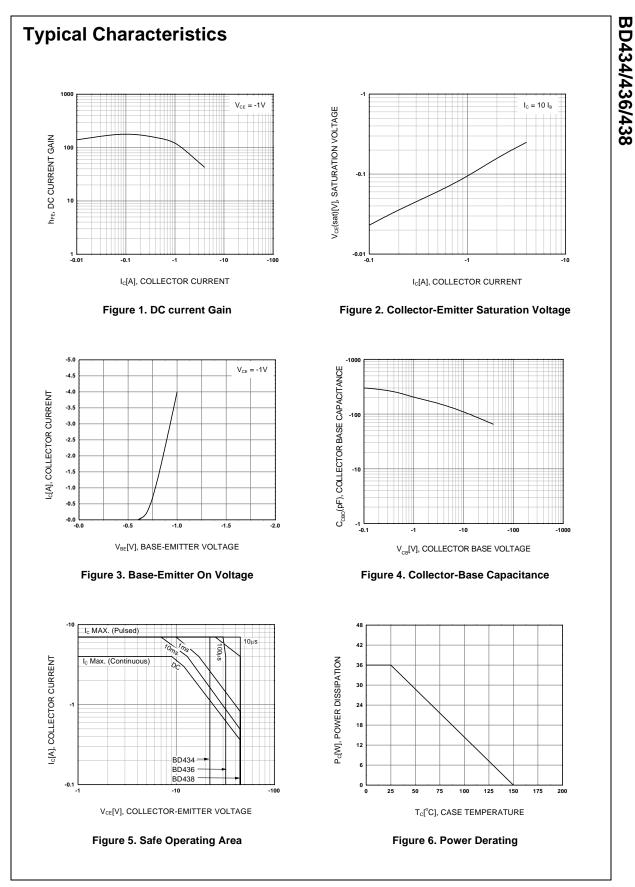
BD434/436/438

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Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V _{CEO} (sus)	Collector-Emitter Sustaining Voltage : BD434	I _C = - 100mA, I _B = 0	- 22			V
	: BD436 : BD438		- 32 - 45			V V
I _{CBO}	Collector Cut-off Current : BD434 : BD436	$V_{CB} = -22V, I_E = 0$ $V_{CB} = -32V, I_E = 0$ $V_{CB} = -45V, I_E = 0$			- 100 - 100	μΑ μΑ
	: BD438	VCB- 100, IE-0			- 100	μΑ
I _{CEO}	Collector Cut-off Current : BD434 : BD436 : BD438	$V_{CE} = -22V, V_{BE} = 0$ $V_{CE} = -32V, V_{BE} = 0$ $V_{CE} = -45V, V_{CE} = 0$			- 100 - 100 - 100	μΑ μΑ
1	Emitter Cut-off Current	$V_{CE} = -45V, V_{BE} = 0$ $V_{EB} = -5V, I_{C} = 0$			- 100	μA mA
l _{EBO} h _{FE}	* DC Current Gain	VEB 5 V, IC - 0			- 1	
"FE	: BD434/436 : BD438 : ALL DEVICE : BD434/436 : BD438	$V_{CE} = -5V, I_C = -10mA$ $V_{CE} = -1V, I_C = -500mA$ $V_{CE} = -1V, I_C = -2A$	40 30 85 50 40	140 140 140		
V _{CE} (sat)	* Collector-Emitter Saturation Voltage : BD434 : BD436 : BD438	I _C = - 2A, I _B = - 0.2A		- 0.2 - 0.2 - 0.2	- 0.5 - 0.5 - 0.6	V V V
V _{BE} (on)	* Base-Emitter ON Voltage : BD434 : BD436 : BD438	V _{CE} = - 1V, I _C = - 2A		0.2	- 1.1 - 1.1 - 1.2	
f _T	Current Gain Bandwidth Product	V _{CE} = - 1V, I _C = - 250mA	3			MHz

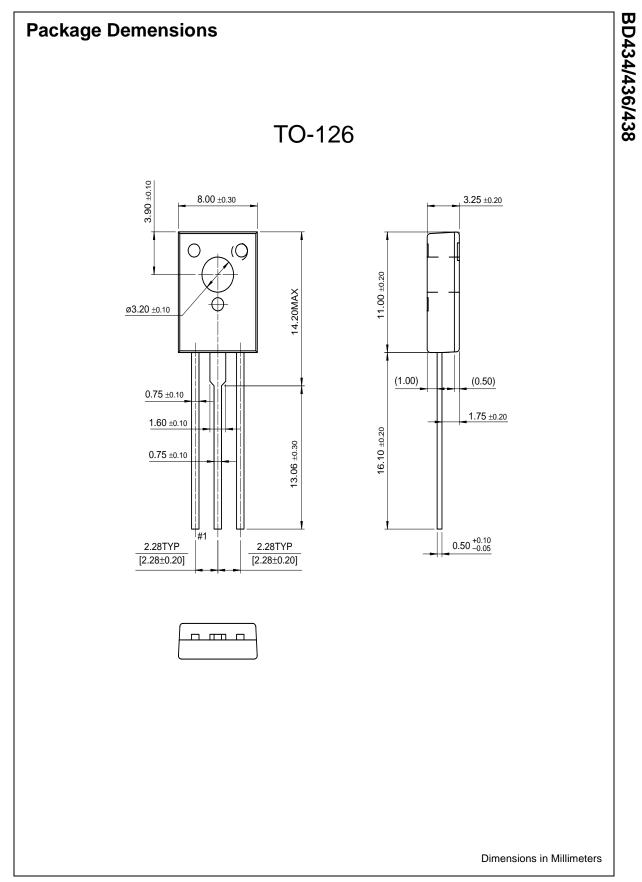
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Rev. A1, June 2001



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